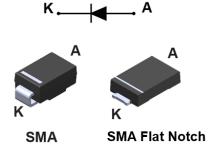


150 V, 1 A power Schottky rectifier





DO-41

Product status STPS1150

Product summary					
Symbol	Values				
I _{F(AV)}	1 A				
V _{RRM}	150 V				
T _{j (max.)}	175 °C				
V _{F(typ.)}	0.62 V				

Features

- Negligible switching losses
- · Low forward voltage drop for higher efficiency and extended battery life
- · Low thermal resistance
- · Surface mount miniature package
- · Avalanche capability
- ECOPACK2 compliant component

Applications

- · Switching diode
- SMPS
- · DC/DC converter
- · Telecom power

Description

This 150 V power Schottky rectifier is ideal for switch mode power supplies on up to 24 V rails and high frequency converters.

Packaged in SMA, SMA Flat Notch and axial, the STPS1150 is optimized for use in consumer and computer applications where low drop forward voltage is required to reduce power dissipation.



1 Characteristics

Table 1. Absolute ratings (limiting values, at 25 °C, unless otherwise specified)

Symbol		Value	Unit		
V_{RRM}	Repetitive peak reverse voltage	je		150	V
I _{F(RMS)}	Forward rms current			15	А
		SMA	T _L = 150 °C		А
$I_{F(AV)}$	$I_{F(AV)}$ Average forward current δ = 0.5, square wave	SMA Flat Notch	T _L = 160 °C	1	
		DO-41	T _L = 150 °C		
	Surge non repetitive forward current	SMA		50	А
I_{FSM}		SMA Flat Notch	t _p = 10 ms sinusoidal	50	
		DO-41		75	
P _{ARM}	Repetitive peak avalanche power	$t_p = 10 \ \mu s, T_j = 12$	25 °C	108	W
T _{stg}	Storage temperature range			-65 to + 175	°C
Tj	Maximum operating junction to	+ 175	°C		

^{1.} $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameter

Symbol		Parameter	Max. value	Unit	
	Junction to lead		SMA	30	
R _{th(j-l)}	Junction to lead		SMA Flat Notch	20	°C/W
	Junction to lead Lead length = 10 mm		DO-41	30	

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I_(1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	Vp = Vpp4	-	0.2	1.0	μΑ
'R'		T _j = 125 °C		-	0.2	1.0	mA
	Forward voltage	T _j = 25 °C	L = 1 A	-	0.78	0.82	
V _F ⁽²⁾		T _j = 125 °C	1F - 1 \(\text{\tiny{\text{\tilit}\\ \text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\tin}\eta}\\ \text{\tinit}\\ \text{\text{\text{\text{\text{\text{\tinit}\\ \text{\ti}\tint{\ti}\tint{\text{\text{\text{\text{\text{\text{\text{\text{\tinit}\\ \text{\texi}\text{\text{\texi}\text{\text{\text{\text{\text{\text{\tin}\tint{\text{\text{\ti}\tint{\text{\texi}\text{\text{\texit{\texitile}\text{\text{\text{\text{\texi}\tint{\tiint{\text{\texitile}}\tinttilef{\tiint{\texitilefti}\text{\tii}\text{\texi	-	0.62	0.67	V
drop	T _j = 25 °C	I- = 2 Δ	-	0.85	0.89	V	
		T _j = 125 °C	1 _F - 2 A	-	0.69	0.75	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.59 \times I_{F(AV)} + 0.08 I_{F^2(RMS)}$

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^{2.} Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$



For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current

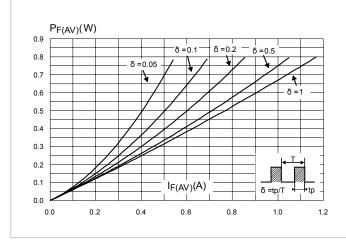


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$)

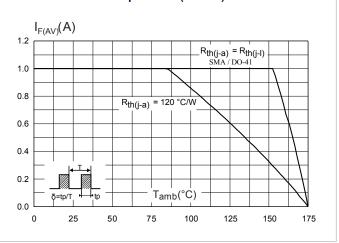


Figure 3. Normalized avalanche power derating versus pulse duration ($T_i = 125$ °C)

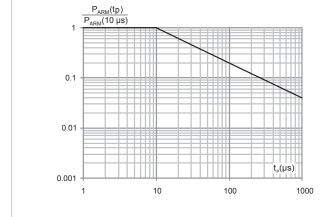
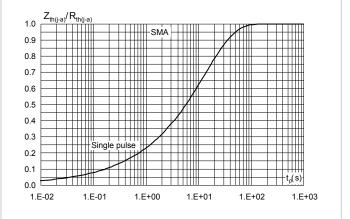


Figure 4. Relative variation of thermal impedance junction to ambient versus pulse duration (SMA)



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Figure 5. Relative variation of thermal impedance junction to ambient versus pulse duration (DO-41)

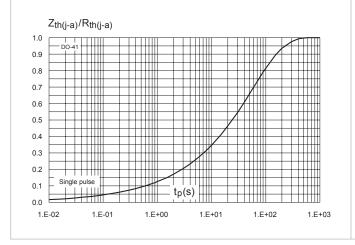


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)

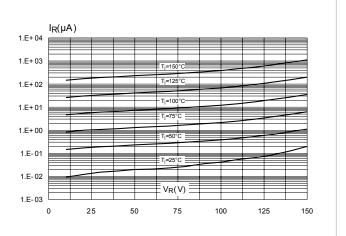


Figure 7. Junction capacitance versus reverse voltage applied (typical values)

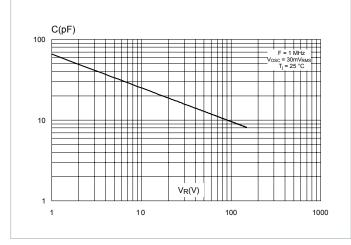


Figure 8. Forward voltage drop versus forward current

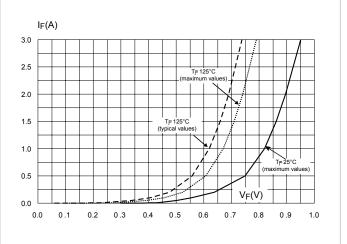


Figure 9. Thermal resistance junction to ambient versus copper surface under each lead (SMA)

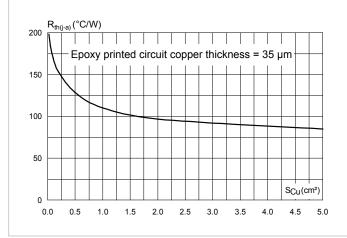
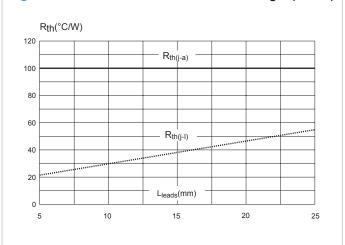


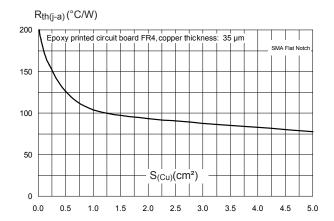
Figure 10. Thermal resistance versus lead length (DO-41)



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Figure 11. Thermal resistance junction to ambient versus copper surface under each lead (SMA Flat Notch)



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SMA package information

- Epoxy meets UL 94, V0
- Cooling method : by conduction (C)

Figure 12. SMA package outline

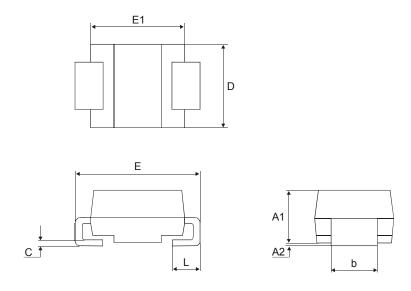


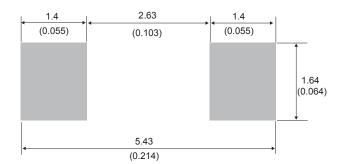
Table 4. SMA package mechanical data

	Dimensions						
Ref.		Millimeters		Inches (for reference only)			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
A1	1.90	-	2.45	0.075	-	0.097	
A2	0.05	-	0.20	0.002	-	0.008	
b	1.25	-	1.65	0.049	-	0.065	
С	0.15	-	0.40	0.006	-	0.016	
D	2.25	-	2.90	0.089	-	0.114	
E	4.80	-	5.35	0.189	-	0.211	
E1	3.95	-	4.60	0.156	-	0.181	
L	0.75	-	1.50	0.030	-	0.059	

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Figure 13. SMA recommended footprint in mm (inches)



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2.2 SMA Flat Notch package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- · Band indicates cathode

Figure 14. SMA Flat Notch package outline

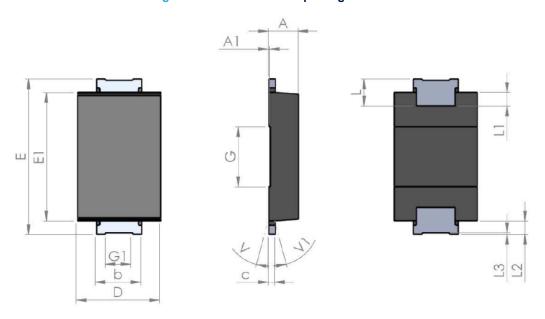


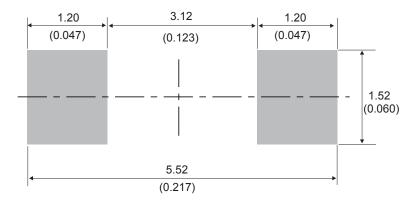
Table 5. SMA Flat Notch package mechanical data

	Dimensions						
Ref.		Millimeters		Inches (for reference only)			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
A1	0.90		1.10	0.035		0.044	
A1		0.05			0.002		
b	1.25		1.65	0.049		0.065	
С	0.15		0.40	0.005		0.016	
D	2.25		2.90	0.088		0.115	
E	5.00		5.35	0.196		0.211	
E1	3.95		4.60	0.155		0.182	
G		2.00			0.079		
G1		0.85			0.033		
L	0.75		1.20	0.029			
L1		0.45			0.018		
L2		0.45			0.018		
L3		0.05			0.002		
V			8°			8°	
V1			8°			8°	

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Figure 15. SMA Flat Notch recommended footprint in mm (inches)



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2.3 DO-41 package information

Epoxy meets UL 94, V0

Figure 16. DO-41 package outline

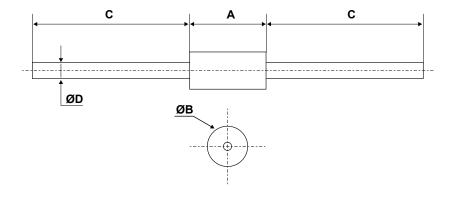


Table 6. DO-41 package mechanical data

	Dimensions							
Ref.		Millimeters		Inch	es (for reference	only)		
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	4.1	-	5.20	0.160	-	0.205		
В	2.00	-	2.71	0.080	-	0.107		
С	25.40	-		1.000	-			
D	0.71	-	0.86	0.028	-	0.0034		

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3 Ordering Information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS1150AFN	A1150	SMA Flat Notch	0.039 g	10 000	Tape and reel
STPS1150A	1150	SMA	0.068 g	5000	Tape and reel
STPS1150	STPS1150	DO-41	0.34 g	2000	Ammopack
STPS1150RL	STPS1150	DO-41	0.34 g	5000	Tape and reel



Revision history

Table 8. Document revision history

Date	Version	Changes
Jul-2003	2A	Last update.
Aug-2004	3	SMA package dimensions update. Reference A1 max. changed from 2.70 mm (0.106) to 2.03 mm (0.080).
31-May-2006	4	Reformatted to current standard. Added ECOPACK statement. Updated SMA footprint in Figure 15. Changed nF to pF in Figure 10.
09-Feb-2011	5	Added STmite and STmite flat package.
15-Apr-2014	6	Updated : Features, Table 2, 3 and Figure 2. Updated Section 2: Package information.
28-Sep-2018	7	Removed STmite and STmite flat package information. Updated Table 1. Absolute ratings (limiting values, at 25 $^{\circ}$ C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus pulse duration (T_j = 125 $^{\circ}$ C).
25-Sep-2019	8	Added Section 2.2 SMA Flat Notch package information.



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